



FZT751

60V PNP MEDIUM POWER TRANSISTOR IN SOT223

Features

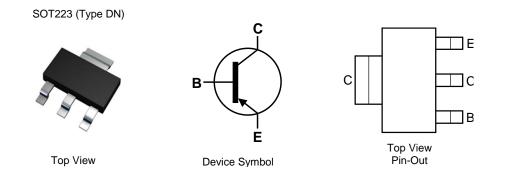
- BV_{CEO} > -60V
- I_C = -3A High Continuous Current
- I_{CM} = -6A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < -300mV @ -1A
- Complementary NPN Type: FZT651
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An Automotive-Compliant Part is Available Under Separate Datasheet (FZT751Q)

Mechanical Data

- Package: SOT223 (Type DN)
- Package Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight: 0.112 grams (Approximate)

Applications

- Lighting
- MOSFET and IGBT gate driving



Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT751TA	FZT751	7	12	1,000
FZT751TC	FZT751	13	12	4,000

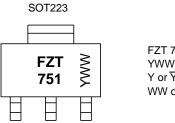
EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:



FZT 751 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 2= 2022) WW or $\overline{W}W$ = Week Code (01~53)



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-80	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ι _C	-3	А
Peak Pulse Current	ICM	-6	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	D-	2	W
Fower Dissipation	(Note 6)	PD	3	W
Thermal Desistance, Junction to Ambient	(Note 5)	D	62.5	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	R _{0JA}	41.7	°C/W
Thermal Resistance, Junction to Leads (Note 7)		R _{θJL}	12.9	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

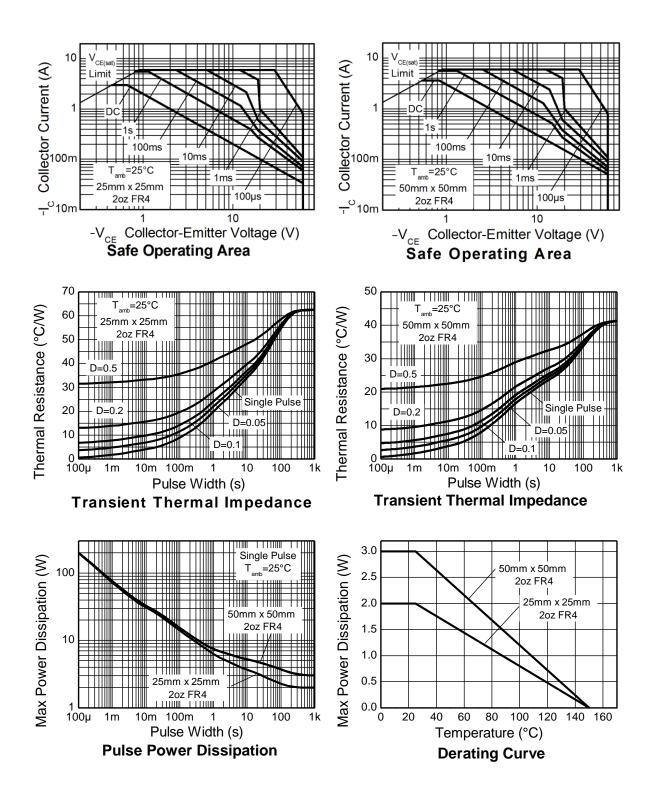
Notes: 5. For a device mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.

6. Same as Note 5, except the device is mounted on 50mm x 50mm 2oz copper.

Thermal resistance from junction to solder-point (at the end of the collector lead).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

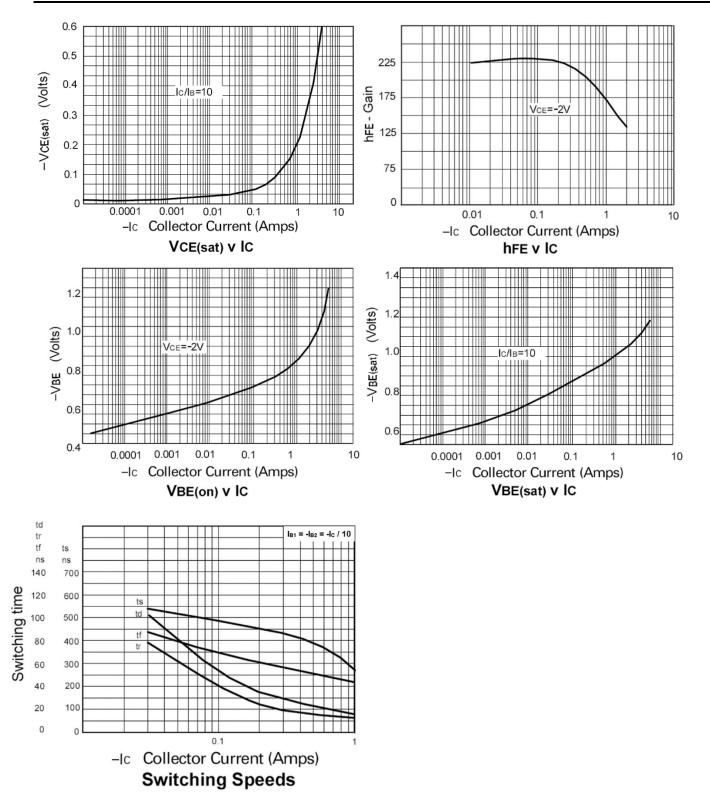
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-80	_	-	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-60	-	-	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BVEBO	-7	-	-	V	I _E = -100μA
Collector Cut-Off Current	I _{СВО}	-	-1	-100	nA	$V_{CB} = -60V$
Collector Cut-On Cutrent		-	-	-10	μA	$V_{CB} = -60V, T_{amb} = +100^{\circ}C$
Emitter Cut-Off Current	I _{EBO}	-	-1	-20	nA	$V_{EB} = -6V$
Collector-Emitter Saturation Voltage (Note 9)		-	-0.15	-0.3	V	I _C = -1A, I _B = -100mA
Collector-Emilier Saturation Voltage (Note 9)	V _{CE(sat)}	-	-0.45	-0.6	v	I _C = -3A, I _B = -300mA
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	-	-0.9	-1.25	V	I _C = -1A, I _B = -100mA
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	-	-0.8	-1.0	V	$I_{C} = -1A, V_{CE} = -2V$
	h _{FE}	70	200	-		I _C = -50mA, V _{CE} = -2V
DC Current Cain (Note 0)		100	200	300		$I_{C} = -500 \text{mA}, V_{CE} = -2 \text{V}$
DC Current Gain (Note 9)		80	170	-	_	$I_{C} = -1A, V_{CE} = -2V$
		40	150	-		$I_{C} = -2A, V_{CE} = -2V$
Current Gain-Bandwidth Product	f _T	100	140	-	MHz	V _{CE} = -5V, I _C = -100mA f = 100MHz
Turn-On Time	t _{on}	-	40	-	ns	$V_{CC} = -10V, I_{C} = -500mA$
Turn-Off Time	t _{off}	-	450	-	ns	$I_{B1} = -I_{B2} = -50 \text{mA}$
Output Capacitance	C _{obo}	-	-	30	pF	V _{CB} = -10V, f = 1MHz

Note: 9. Measured under pulsed conditions. Pulse width \leq 300 µs. Duty cycle \leq 2%.



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Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

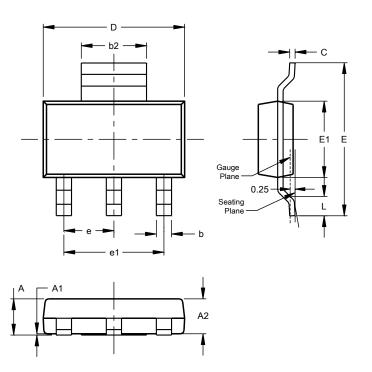




FZT751

Package Outline Dimensions

Please see https://www.diodes.com/design/support/packaging/ for the latest version.

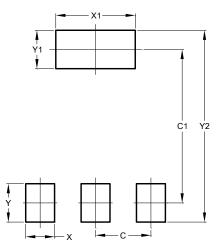


SOT223 (Type DN)					
Dim	Min	Max			
		IVIAN	Тур		
Α		1.70			
A1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
c	0.20	0.32			
D	6.30	6.70			
ш	6.70	7.30			
E1	3.30	3.70			
e			2.30		
e1			4.60		
L	0.85				
All Dimensions in mm					

Suggested Pad Layout

Please see https://www.diodes.com/design/support/packaging/ for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

SOT223 (Type DN)



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